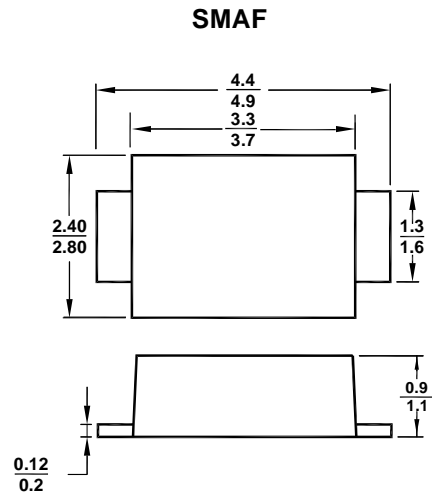


SM5817F THRU SM5819F-HAF

Surface Mount Schottky Barrier Rectifier
Reverse Voltage - 20 to 40 V
Forward Current - 1 A

Features

- Halogen and Antimony Free(HAF), RoHS compliant



All Dimensions in mm

Absolute Maximum Ratings and Characteristics

Ratings at 25°C ambient temperature unless otherwise specified, single phase, half wave, resistive or inductive load. For capacitive load, derate by 20%

Parameter	Symbols	SM5817F	SM5818F	SM5819F	Units
	Marking	SS12	SS13	SS14	-
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	20	30	40	V
Maximum RMS Voltage	V_{RMS}	14	21	28	V
Maximum DC Blocking Voltage	V_{DC}	20	30	40	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	1			A
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load(JEDEC methode)	I_{FSM}	25			A
Maximum Instantaneous Forward Voltage at $I_F = 1 A$ at $I_F = 3 A$	V_F	0.45 0.75	0.55 0.875	0.6 0.9	V
Maximum Instantaneous Reverse Current at Rated DC Blocking Voltage ¹⁾	I_R	0.5 10			mA
Typical Junction Capacitance ²⁾	C_J	110			pF
Typical Thermal Resistance, Junction to Ambient ³⁾	$R_{\theta JA}$	75			°C/W
Operating Junction Temperature Range	T_J	- 55 to + 125			°C
Storage Temperature Range	T_{stg}	- 55 to + 150			°C

¹⁾ Pulse test: 300 μ s pulse width, 1% duty cycle

²⁾ Mearsured at 1 MHz and reverse voltage of 4 V

³⁾ Thermal resistance junction to ambient 0.24" X 0.24"(6 X 6 mm) copper pads to each terminals

SM5817F THRU SM5819F-HAF

FIG.1-FORWARD CURRENT DERATING CURVE

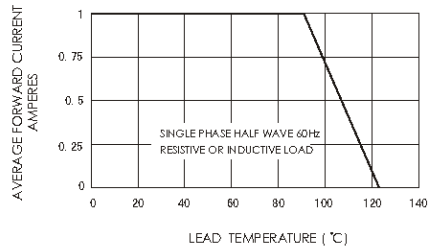


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

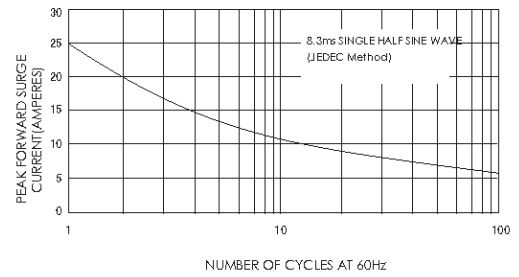


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

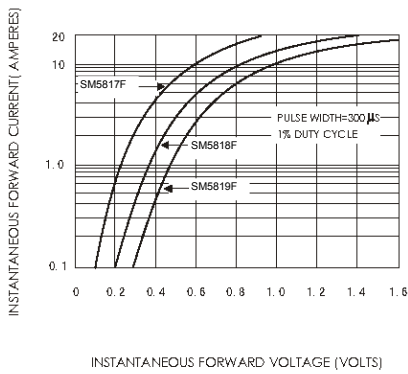


FIG.4-TYPICAL REVERSE CHARACTERISTICS

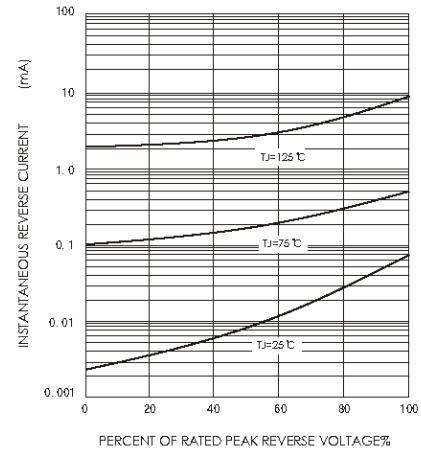


FIG.5-TYPICAL JUNCTION CAPACITANCE

